

## General Description

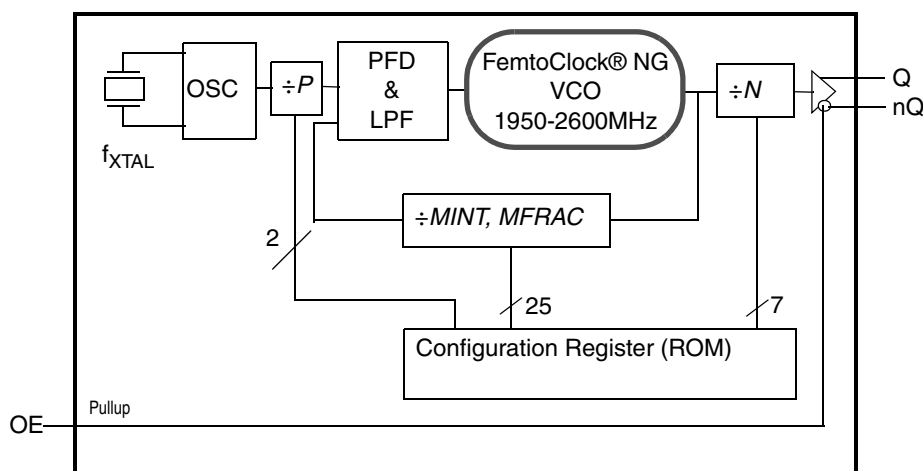
The ICS8N3S270 is a Frequency-Programmable Crystal Oscillator with very flexible frequency programming capabilities. The device uses IDT's fourth generation FemtoClock® NG technology for an optimum of high clock frequency and low phase noise performance. The device accepts 2.5V or 3.3V supply and is packaged in a small, lead-free (RoHS 6) 6-lead ceramic 5mm x 7mm x 1.55mm package.

The device can be factory programmed to any frequency in the range from 15.476MHz to 866.67MHz and from 975MHz to 1,300MHz and supports a very high degree of frequency precision of 218Hz or better. The extended temperature range supports wireless infrastructure, telecommuni- cation and networking end equipment requirements.

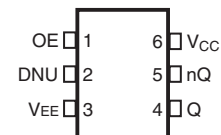
## Features

- Fourth generation FemtoClock® NG technology
- Factory-programmable clock output frequency from 15.476MHz to 866.67MHz and from 975MHz to 1,300MHz
- Frequency programming resolution is 218Hz and better
- One 2.5V or 3.3V LVPECL clock output
- Output enable control (positive polarity), LVCMOS/LVTTL compatible
- RMS phase jitter @ 156.25MHz (12kHz - 20MHz): 0.24ps (typical), integer PLL feedback configuration
- RMS phase jitter @ 156.25MHz (1kHz - 40MHz): 0.27ps (typical), integer PLL feedback configuration
- 2.5V or 3.3V supply
- -40°C to 85°C ambient operating temperature
- Available in a lead-free (RoHS 6) 6-pin ceramic package

## Block Diagram



## Pin Assignment



**IDT8N3S270**  
6-lead ceramic 5mm x 7mm x 1.55mm  
package body  
CD Package  
Top View

## Pin Description and Characteristic Tables

**Table 1. Pin Descriptions**

| Number | Name            | Type   |        | Description                                                                  |
|--------|-----------------|--------|--------|------------------------------------------------------------------------------|
| 1      | OE              | Input  | Pullup | Output enable pin. See Table 3A for function. LVCMOS/LVTTL interface levels. |
| 2      | DNU             |        |        | Do not use (factory use only).                                               |
| 3      | V <sub>EE</sub> | Power  |        | Negative power supply.                                                       |
| 4, 5   | Q, nQ           | Output |        | Differential clock output. LVPECL interface levels.                          |
| 6      | V <sub>CC</sub> | Power  |        | Positive power supply.                                                       |

NOTE: *Pullup* refers to an internal input resistor. See Table 2, *Pin Characteristics*, for typical values.

**Table 2. Pin Characteristics**

| Symbol              | Parameter             |    | Test Conditions | Minimum | Typical | Maximum | Units |
|---------------------|-----------------------|----|-----------------|---------|---------|---------|-------|
| C <sub>IN</sub>     | Input Capacitance     | OE |                 |         | 5.5     |         | pF    |
| R <sub>PULLUP</sub> | Input Pullup Resistor |    |                 |         | 50      |         | kΩ    |

## Function Tables

**Table 3A. OE Configuration**

| Input       | Output Enable                              |
|-------------|--------------------------------------------|
| OE          |                                            |
| 0           | Outputs Q, nQ are in high-impedance state. |
| 1 (default) | Outputs are enabled.                       |

NOTE: OE is an asynchronous control.

**Table 3B. Output Frequency Range**

|                        |
|------------------------|
| 15.476MHz to 866.67MHz |
| 975MHz to 1,300MHz     |

NOTE: Supported output frequency range. The output frequency can be programmed to any frequency in this range and to a precision of 218Hz or better.

## Principles of Operation

The block diagram consists of the internal 3<sup>RD</sup> overtone crystal and oscillator which provide the reference clock  $f_{XTAL}$  of either 114.285MHz or 100MHz. The PLL includes the FemtoClock NG VCO along with the Pre-divider ( $P$ ), the feedback divider ( $M$ ) and the post divider ( $N$ ). The  $P$ ,  $M$ , and  $N$  dividers determine the output frequency based on the  $f_{XTAL}$  reference. The feedback divider is fractional supporting a huge number of output frequencies. The configuration of the feedback divider to integer-only values results in an improved output phase noise characteristics at the expense of the range of output frequencies. Internal registers are used to hold one factory pre-set  $P$ ,  $M$ , and  $N$  configuration setting. The  $P$ ,  $M$ , and  $N$  frequency configuration supports an output frequency range from 15.476MHz to 866.67MHz and from 975MHz to 1,300MHz.

The devices use the fractional feedback divider with a delta-sigma modulator for noise shaping and robust frequency synthesis capability. The relatively high reference frequency minimizes phase noise generated by frequency multiplication and allows more efficient shaping of noise by the delta-sigma modulator.

The output frequency is determined by the 2-bit pre-divider ( $P$ ), the feedback divider ( $M$ ) and the 7-bit post divider ( $N$ ). The feedback divider ( $M$ ) consists of both a 7-bit integer portion ( $MINT$ ) and an 18-bit fractional portion ( $MFRAC$ ) and provides the means for high-resolution frequency generation. The output frequency  $f_{OUT}$  is calculated by:

$$f_{OUT} = f_{XTAL} \cdot \frac{1}{P \cdot N} \cdot \left[ MINT + \frac{MFRAC + 0.5}{2^{18}} \right]$$

## Frequency Configuration

An order code is assigned to each frequency configuration programmed by the factory (default frequencies). For more information on the available default frequencies and order codes, please see the Ordering Information section in this document. For available order codes, see the *FemtoClock NG Ceramic-Package XO and VCXO Ordering Product Information* document.

For more information on programming capabilities of the device for custom frequency and pull-range configurations, see the *FemtoClock NG Ceramic 5x7 Module Programming Guide*.

## Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

| Item                                                  | Rating                   |
|-------------------------------------------------------|--------------------------|
| Supply Voltage, $V_{CC}$                              | 3.63V                    |
| Inputs, $V_I$                                         | -0.5V to $V_{CC} + 0.5V$ |
| Outputs, $I_O$<br>Continuous Current<br>Surge Current | 50mA<br>100mA            |
| Package Thermal Impedance, $\theta_{JA}$              | 49.4°C/W (0 mps)         |
| Storage Temperature, $T_{STG}$                        | -65°C to 150°C           |

## DC Electrical Characteristics

**Table 4A. Power Supply DC Characteristics,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^\circ C$  to  $85^\circ C$**

| Symbol   | Parameter            | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|----------------------|-----------------|---------|---------|---------|-------|
| $V_{CC}$ | Power Supply Voltage |                 | 3.135   | 3.3     | 3.465   | V     |
| $I_{EE}$ | Power Supply Current |                 |         | 123     | 148     | mA    |

**Table 4B. Power Supply DC Characteristics,  $V_{CC} = 2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^\circ C$  to  $85^\circ C$**

| Symbol   | Parameter            | Test Conditions | Minimum | Typical | Maximum | Units |
|----------|----------------------|-----------------|---------|---------|---------|-------|
| $V_{CC}$ | Power Supply Voltage |                 | 2.375   | 2.5     | 2.625   | V     |
| $I_{EE}$ | Power Supply Current |                 |         | 119     | 143     | mA    |

**Table 4C. LVPECL DC Characteristics,  $V_{CC} = 3.3V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^\circ C$  to  $85^\circ C$**

| Symbol      | Parameter                         | Test Conditions | Minimum        | Typical | Maximum        | Units |
|-------------|-----------------------------------|-----------------|----------------|---------|----------------|-------|
| $V_{OH}$    | Output High Voltage; NOTE 1       |                 | $V_{CC} - 1.4$ |         | $V_{CC} - 0.8$ | V     |
| $V_{OL}$    | Output Low Voltage; NOTE 1        |                 | $V_{CC} - 2.0$ |         | $V_{CC} - 1.6$ | V     |
| $V_{SWING}$ | Peak-to-Peak Output Voltage Swing |                 | 0.6            |         | 1.0            | V     |

NOTE 1: Outputs terminated with 50Ω to  $V_{CC} - 2V$ .

**Table 4D. LVPECL DC Characteristics,  $V_{CC} = 2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^\circ C$  to  $85^\circ C$**

| Symbol      | Parameter                         | Test Conditions | Minimum        | Typical | Maximum        | Units |
|-------------|-----------------------------------|-----------------|----------------|---------|----------------|-------|
| $V_{OH}$    | Output High Voltage; NOTE 1       |                 | $V_{CC} - 1.4$ |         | $V_{CC} - 0.8$ | V     |
| $V_{OL}$    | Output Low Voltage; NOTE 1        |                 | $V_{CC} - 2.0$ |         | $V_{CC} - 1.5$ | V     |
| $V_{SWING}$ | Peak-to-Peak Output Voltage Swing |                 | 0.4            |         | 1.0            | V     |

NOTE 1: Outputs terminated with 50Ω to  $V_{CC} - 2V$ .

**Table 4E. LVCMOS/LVTTL DC Characteristic,  $V_{CC} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^{\circ}C$  to  $85^{\circ}C$** 

| Symbol   | Parameter          |    | Test Conditions                               | Minimum | Typical | Maximum        | Units   |
|----------|--------------------|----|-----------------------------------------------|---------|---------|----------------|---------|
| $V_{IH}$ | Input High Voltage |    | $V_{CC} = 3.3V$                               | 2       |         | $V_{CC} + 0.3$ | V       |
|          |                    |    | $V_{CC} = 2.5V$                               | 1.7     |         | $V_{CC} + 0.3$ | V       |
| $V_{IL}$ | Input Low Voltage  |    | $V_{CC} = V_{IN} = 3.465V$                    | -0.3    |         | 0.8            | V       |
|          |                    |    | $V_{CC} = V_{IN} = 2.5V$                      | -0.3    |         | 0.7            | V       |
| $I_{IH}$ | Input High Current | OE | $V_{CC} = V_{IN} = 3.465V$ or $2.625V$        |         |         | 5              | $\mu A$ |
| $I_{IL}$ | Input Low Current  | OE | $V_{CC} = 3.465V$ or $2.625V$ , $V_{IN} = 0V$ | -150    |         |                | $\mu A$ |

## AC Electrical Characteristics

**Table 5. AC Characteristics,  $V_{CC} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $V_{EE} = 0V$ ,  $T_A = -40^\circ C$  to  $85^\circ C$**

| Symbol                     | Parameter                                                                                              | Test Conditions                                      | Minimum | Typical | Maximum   | Units  |
|----------------------------|--------------------------------------------------------------------------------------------------------|------------------------------------------------------|---------|---------|-----------|--------|
| $f_{OUT}$                  | Output Frequency Q, nQ                                                                                 |                                                      | 15.476  |         | 866.67    | MHz    |
|                            |                                                                                                        |                                                      | 975     |         | 1,300     | MHz    |
| $f_I$                      | Initial Accuracy                                                                                       | Measured @ $25^\circ C$                              |         |         | $\pm 10$  | ppm    |
| $f_S$                      | Temperature Stability                                                                                  | Option code = A or B                                 |         |         | $\pm 100$ | ppm    |
|                            |                                                                                                        | Option code = E or F                                 |         |         | $\pm 50$  | ppm    |
|                            |                                                                                                        | Option code = K or L                                 |         |         | $\pm 20$  | ppm    |
| $f_A$                      | Aging                                                                                                  | Frequency drift over 10 year life                    |         |         | $\pm 3$   | ppm    |
|                            |                                                                                                        | Frequency drift over 15 year life                    |         |         | $\pm 5$   | ppm    |
| $f_T$                      | Total Stability                                                                                        | Option code A, B (10 year life)                      |         |         | $\pm 113$ | ppm    |
|                            |                                                                                                        | Option code E, F (10 year life)                      |         |         | $\pm 63$  | ppm    |
|                            |                                                                                                        | Option code K, L (10 year life)                      |         |         | $\pm 33$  | ppm    |
| $\dot{f}_{jit}(cc)$        | Cycle-to-Cycle Jitter; NOTE 1                                                                          |                                                      |         |         | 30        | ps     |
| $\dot{f}_{jit}(per)$       | RMS Period Jitter; NOTE 1                                                                              |                                                      |         | 1.9     | 2.8       | ps     |
| $\dot{f}_{jit}(\emptyset)$ | RMS Phase Jitter (Random);<br>Fractional PLL feedback and<br>$f_{XTAL} = 100MHz$ (2xxx order codes)    | $17MHz \leq f_{OUT} \leq 1300MHz$ ,<br>NOTE 2, 3, 4  |         | 0.497   | 0.882     | ps     |
|                            | RMS Phase Jitter (Random);<br>Integer PLL feedback and<br>$f_{XTAL} = 100MHz$ (1xxx order codes)       | $500MHz \leq f_{OUT} \leq 1300MHz$ ,<br>NOTE 2, 3, 4 |         | 0.232   | 0.322     | ps     |
|                            |                                                                                                        | $125MHz \leq f_{OUT} < 500MHz$ ,<br>NOTE 2, 3, 4     |         | 0.250   | 0.384     | ps     |
|                            |                                                                                                        | $17MHz \leq f_{OUT} < 125MHz$ ,<br>NOTE 2, 3, 4      |         | 0.275   | 0.405     | ps     |
|                            |                                                                                                        | $f_{OUT} = 156.25MHz$ , NOTE 2, 3, 4                 |         | 0.242   | 0.311     | ps     |
|                            |                                                                                                        | $f_{OUT} = 156.25MHz$ , NOTE 2, 3, 5                 |         | 0.275   | 0.359     | ps     |
|                            | RMS Phase Jitter (Random)<br>Fractional PLL feedback and<br>$f_{XTAL} = 114.285MHz$ (0xxx order codes) | $17MHz \leq f_{OUT} \leq 1300MHz$ ,<br>NOTE 2, 3, 4  |         | 0.474   | 0.986     | ps     |
| $\Phi_N(100)$              | Single-side band phase noise,<br>100Hz from Carrier                                                    | 156.25MHz                                            |         | -92     |           | dBc/Hz |
| $\Phi_N(1k)$               | Single-side band phase noise,<br>1kHz from Carrier                                                     | 156.25MHz                                            |         | -120    |           | dBc/Hz |
| $\Phi_N(10k)$              | Single-side band phase noise,<br>10kHz from Carrier                                                    | 156.25MHz                                            |         | -131    |           | dBc/Hz |
| $\Phi_N(100k)$             | Single-side band phase noise,<br>100kHz from Carrier                                                   | 156.25MHz                                            |         | -138    |           | dBc/Hz |
| $\Phi_N(1M)$               | Single-side band phase noise,<br>1MHz from Carrier                                                     | 156.25MHz                                            |         | -139    |           | dBc/Hz |
| $\Phi_N(10M)$              | Single-side band phase noise,<br>10MHz from Carrier                                                    | 156.25MHz                                            |         | -154    |           | dBc/Hz |
| $t_R / t_F$                | Output Rise/Fall Time                                                                                  | 20% to 80%                                           | 50      |         | 450       | ps     |
| odc                        | Output Duty Cycle                                                                                      |                                                      | 47      |         | 53        | %      |
| $t_{STARTUP}$              | Device startup time after power up                                                                     |                                                      |         |         | 20        | ms     |

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE: XTAL parameters (initial accuracy, temperature stability, aging and total stability) are guaranteed by manufacturing.

NOTE 1: This parameter is defined in accordance with JEDEC standard 65.

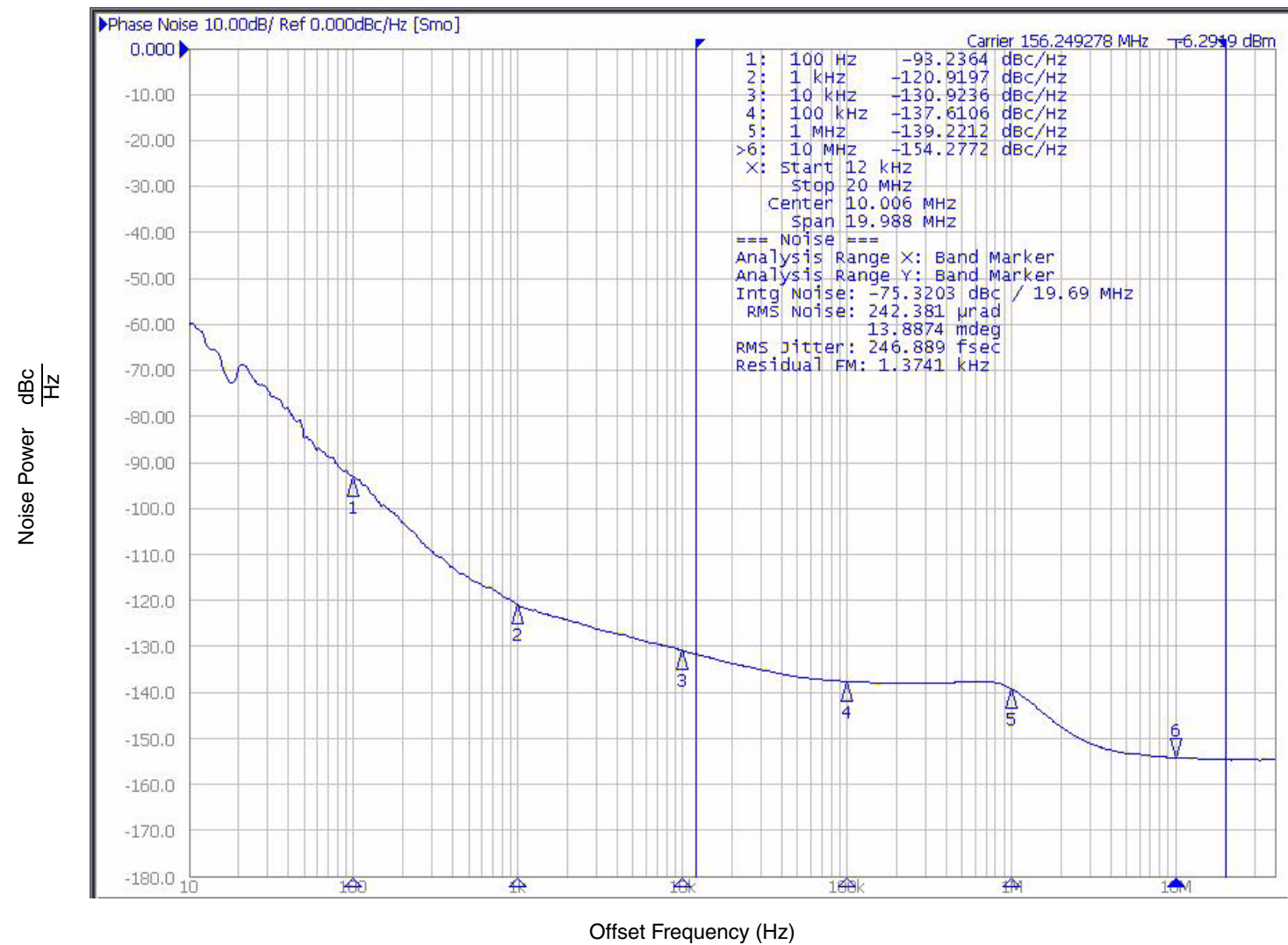
NOTE 2: Refer to the phase noise plot.

NOTE 3: Please see the FemtoClockNG Ceramic 5x7 Modules Programming guide for more information on PLL feedback modes and the optimum configuration for phase noise. Integer PLL feedback is the default operation for the dddd = 1xxx order codes.

NOTE 4: Integration range: 12kHz - 20MHz.

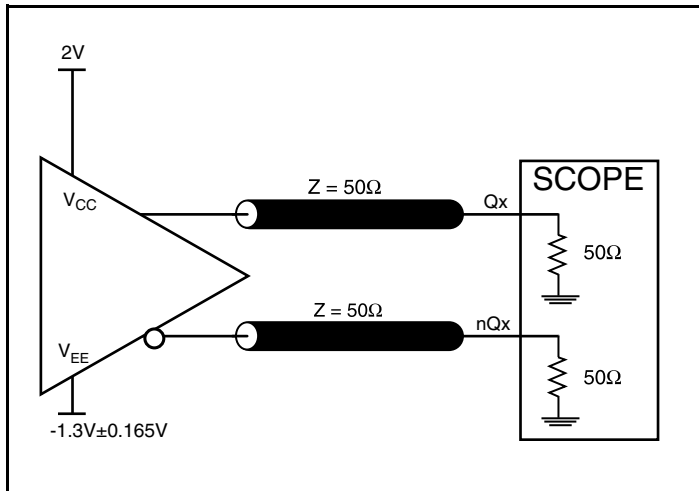
NOTE 5: Integration range: 1kHz - 40MHz.

Typical Phase Noise at 156.25MHz (12kHz - 20MHz)

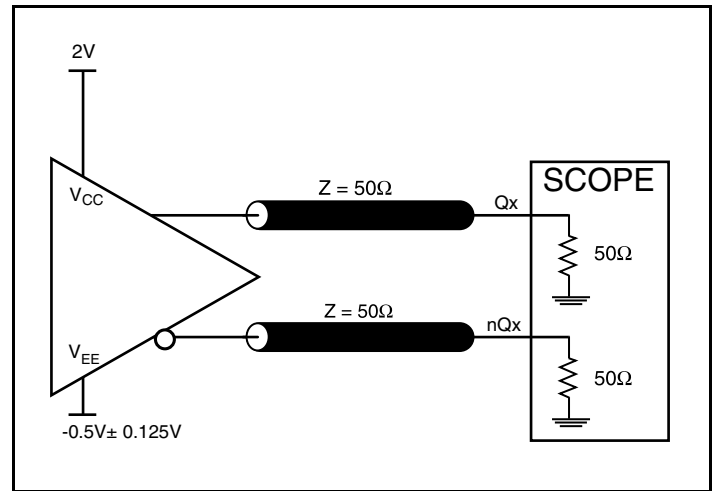




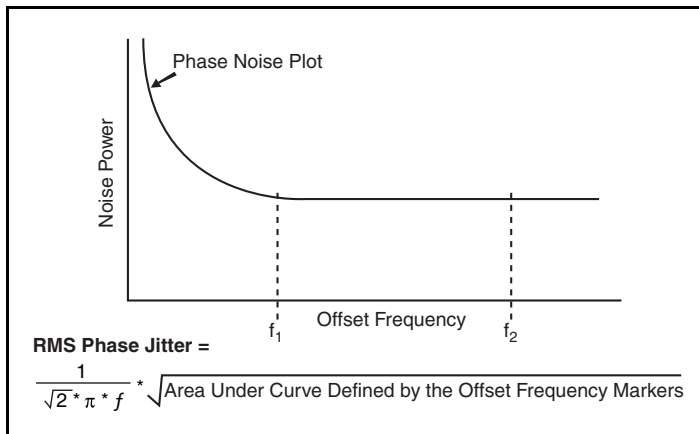
## Parameter Measurement Information



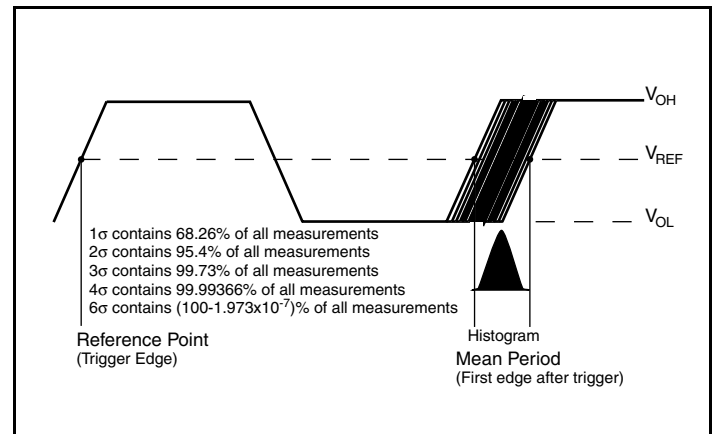
3.3V LVPECL Output Load AC Test Circuit



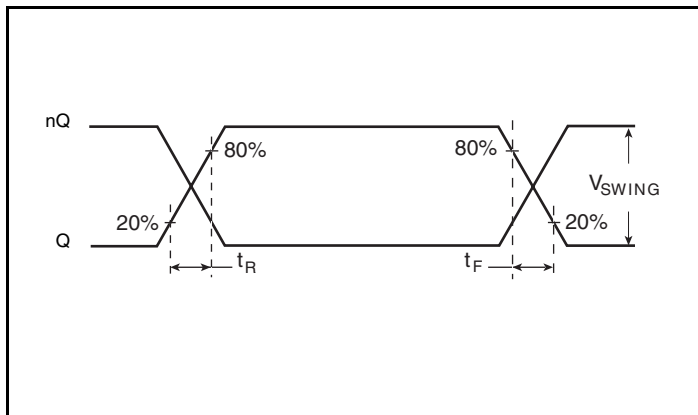
2.5V LVPECL Output Load AC Test Circuit



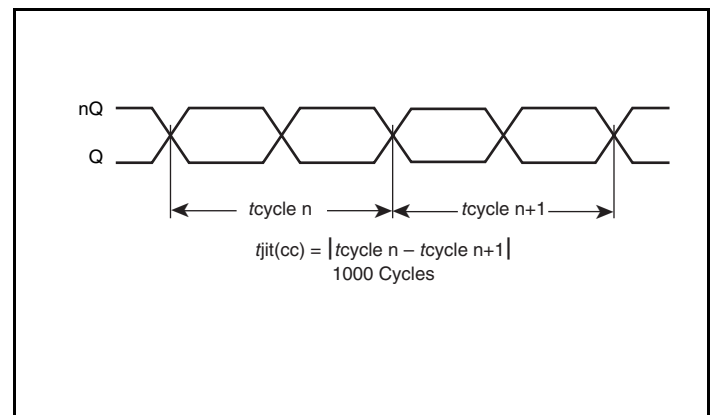
RMS Phase Jitter



Period Jitter

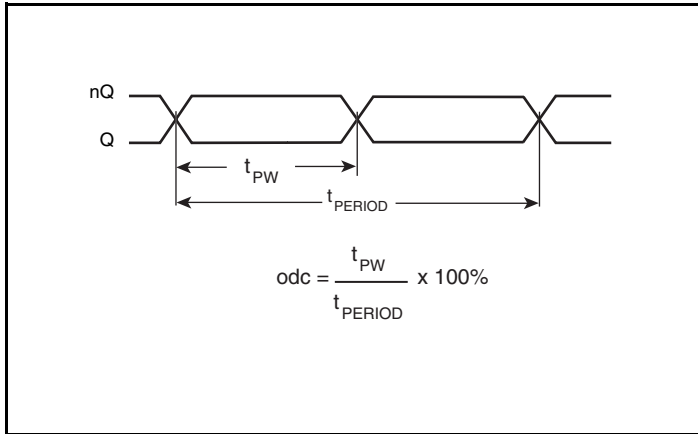


Output Rise/Fall Time



Cycle-to-Cycle Jitter

## Parameter Measurement Information, continued



Output Duty Cycle/Pulse Width/Period

## Applications Information

### Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive  $50\Omega$

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion.

*Figures 1A and 1B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

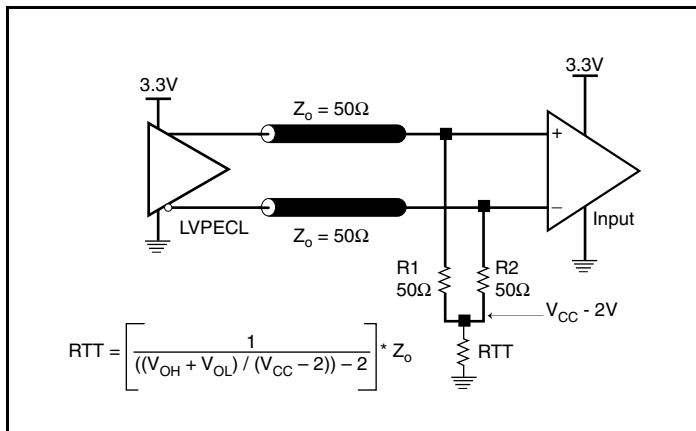


Figure 1A. 3.3V LVPECL Output Termination

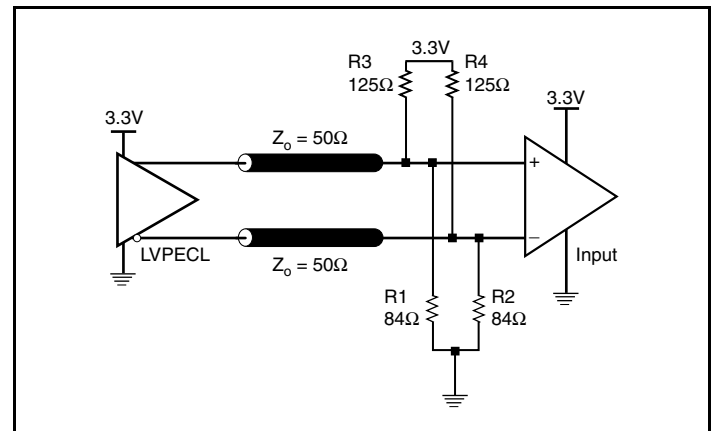


Figure 1B. 3.3V LVPECL Output Termination



## Schematic Layout

Figure 3 shows an example of IDT8N3270 application schematic. In this example, the device is operated at  $V_{CC} = 3.3V$ . As with any high speed analog circuitry, the power supply pins are vulnerable to noise. To achieve optimum jitter performance, power supply isolation is required.

In order to achieve the best possible filtering, it is recommended that the placement of the filter components be on the device side of the PCB as close to the power pins as possible. If space is limited, the 0.1uF capacitor in each power pin filter should be placed on the device side of the PCB and the other components can be placed on the opposite side.

Power supply filter recommendations are a general guideline to be used for reducing external noise from coupling into the devices. The filter performance is designed for wide range of noise frequencies. This low-pass filter starts to attenuate noise at approximately 10kHz. If a specific frequency noise component is known, such as switching power supply frequencies, it is recommended that component values be adjusted and if required, additional filtering be added. Additionally, good general design practices for power plane voltage stability suggests adding bulk capacitances in the local area of all devices.

The schematic example focuses on functional connections and is not configuration specific. Refer to the pin description and functional tables in the datasheet to ensure the logic control inputs are properly set.

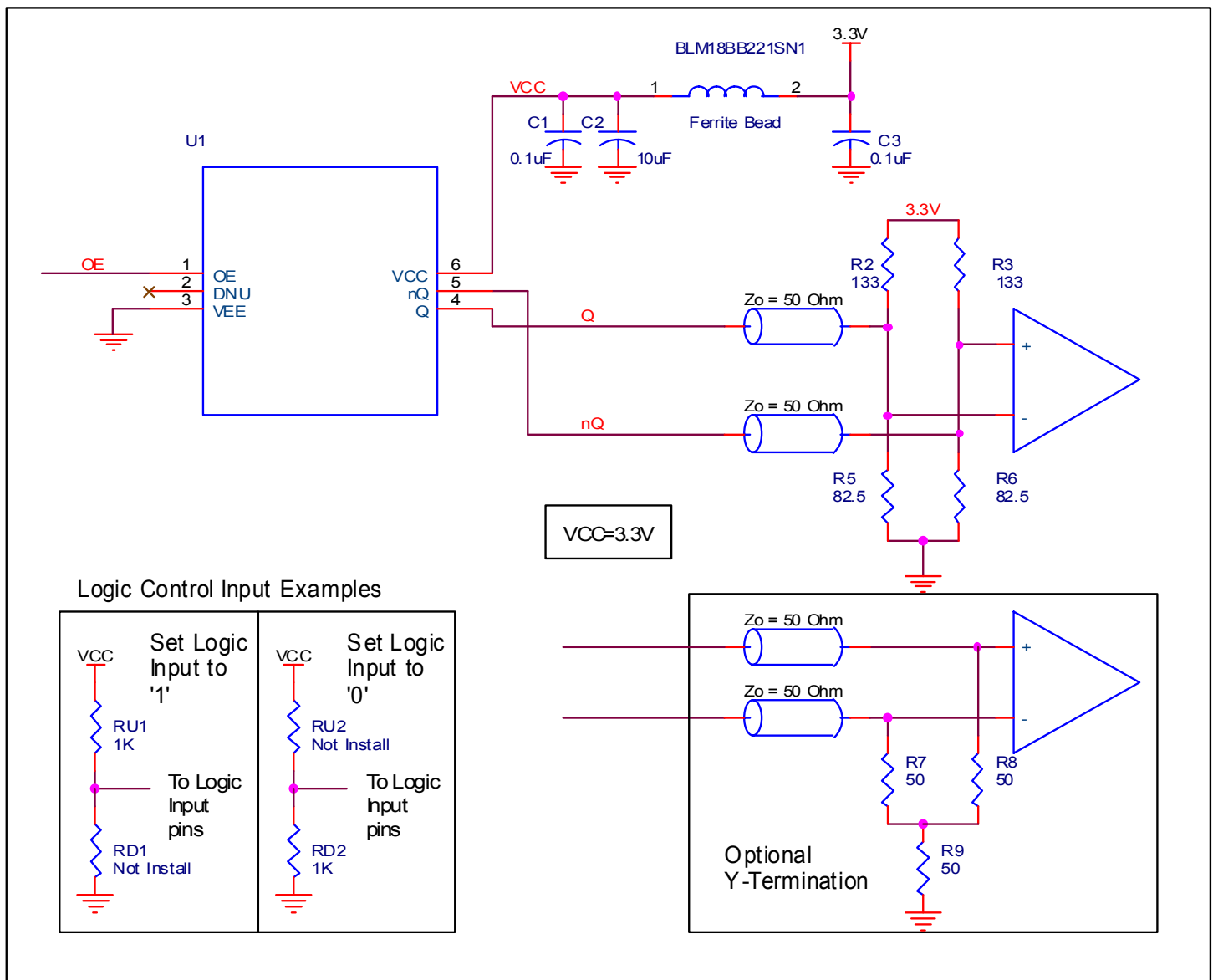


Figure 3. IDT8N3S270 Application Schematic

## Power Considerations

This section provides information on power dissipation and junction temperature for the IDT8N3S270. Equations and example calculations are also provided.

### 1. Power Dissipation.

The total power dissipation for the IDT8N3S270 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for  $V_{CC} = 3.465V$ , which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)<sub>MAX</sub> =  $V_{CC\_MAX} * I_{EE\_MAX} = 3.465V * 148mA = 512.82mW$
- Power (outputs)<sub>MAX</sub> = **32mW/Loaded Output pair**

**Total Power**<sub>MAX</sub> (3.465V, with all outputs switching) =  $512.82mW + 32mW = 544.82mW$

### 2. Junction Temperature.

Junction temperature,  $T_j$ , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature,  $T_j$ , to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for  $T_j$  is as follows:  $T_j = \theta_{JA} * Pd\_total + T_A$

$T_j$  = Junction Temperature

$\theta_{JA}$  = Junction-to-Ambient Thermal Resistance

$Pd\_total$  = Total Device Power Dissipation (example calculation is in section 1 above)

$T_A$  = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance  $\theta_{JA}$  must be used. Assuming no air flow and a multi-layer board, the appropriate value is 49.4°C/W per Table 6 below.

Therefore,  $T_j$  for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ C + 0.545W * 49.4^\circ C/W = 111.9^\circ C. \text{ This is below the limit of } 125^\circ C.$$

This calculation is only an example.  $T_j$  will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

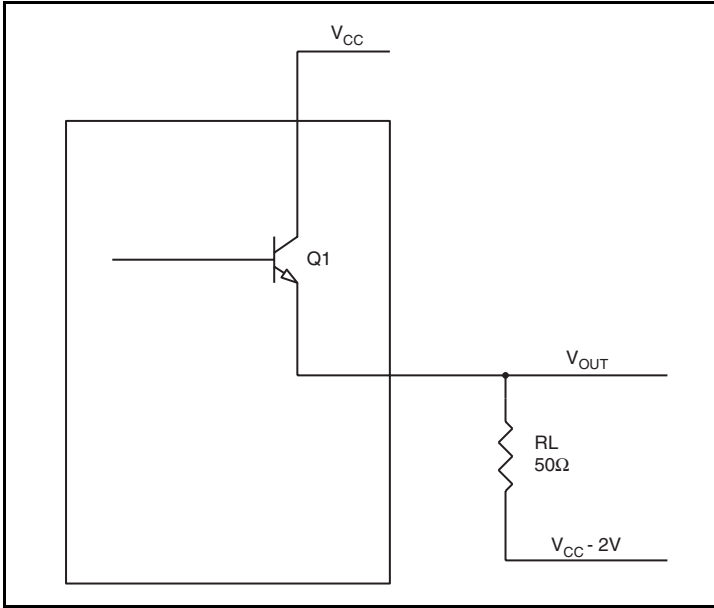
**Table 6. Thermal Resistance  $\theta_{JA}$  for 6 Lead Ceramic 5mm x 7mm Package, Forced Convection**

| Meters per Second                           | $\theta_{JA}$ by Velocity |          |          |
|---------------------------------------------|---------------------------|----------|----------|
|                                             | 0                         | 1        | 2        |
| Multi-Layer PCB, JEDEC Standard Test Boards | 49.4°C/W                  | 44.2°C/W | 42.1°C/W |

### 3. Calculations and Equations.

The purpose of this section is to calculate the power dissipation for the LVPECL output pair.

LVPECL output driver circuit and termination are shown in *Figure 4*.



**Figure 4. LVPECL Driver Circuit and Termination**

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of  $V_{CC} - 2V$ .

- For logic high,  $V_{OUT} = V_{OH\_MAX} = V_{CC\_MAX} - 0.8V$   
( $V_{CC\_MAX} - V_{OH\_MAX}$ ) = **0.8V**
- For logic low,  $V_{OUT} = V_{OL\_MAX} = V_{CC\_MAX} - 1.6V$   
( $V_{CC\_MAX} - V_{OL\_MAX}$ ) = **1.6V**

$Pd\_H$  is power dissipation when the output drives high.

$Pd\_L$  is the power dissipation when the output drives low.

$$Pd\_H = [(V_{OH\_MAX} - (V_{CC\_MAX} - 2V))/R_L] * (V_{CC\_MAX} - V_{OH\_MAX}) = [(2V - (V_{CC\_MAX} - V_{OH\_MAX}))/R_L] * (V_{CC\_MAX} - V_{OH\_MAX}) = [(2V - 0.8V)/50\Omega] * 0.8V = \mathbf{19.2mW}$$

$$Pd\_L = [(V_{OL\_MAX} - (V_{CC\_MAX} - 2V))/R_L] * (V_{CC\_MAX} - V_{OL\_MAX}) = [(2V - (V_{CC\_MAX} - V_{OL\_MAX}))/R_L] * (V_{CC\_MAX} - V_{OL\_MAX}) = [(2V - 1.6V)/50\Omega] * 1.6V = \mathbf{12.8mW}$$

$$\text{Total Power Dissipation per output pair} = Pd\_H + Pd\_L = \mathbf{32mW}$$

## Reliability Information

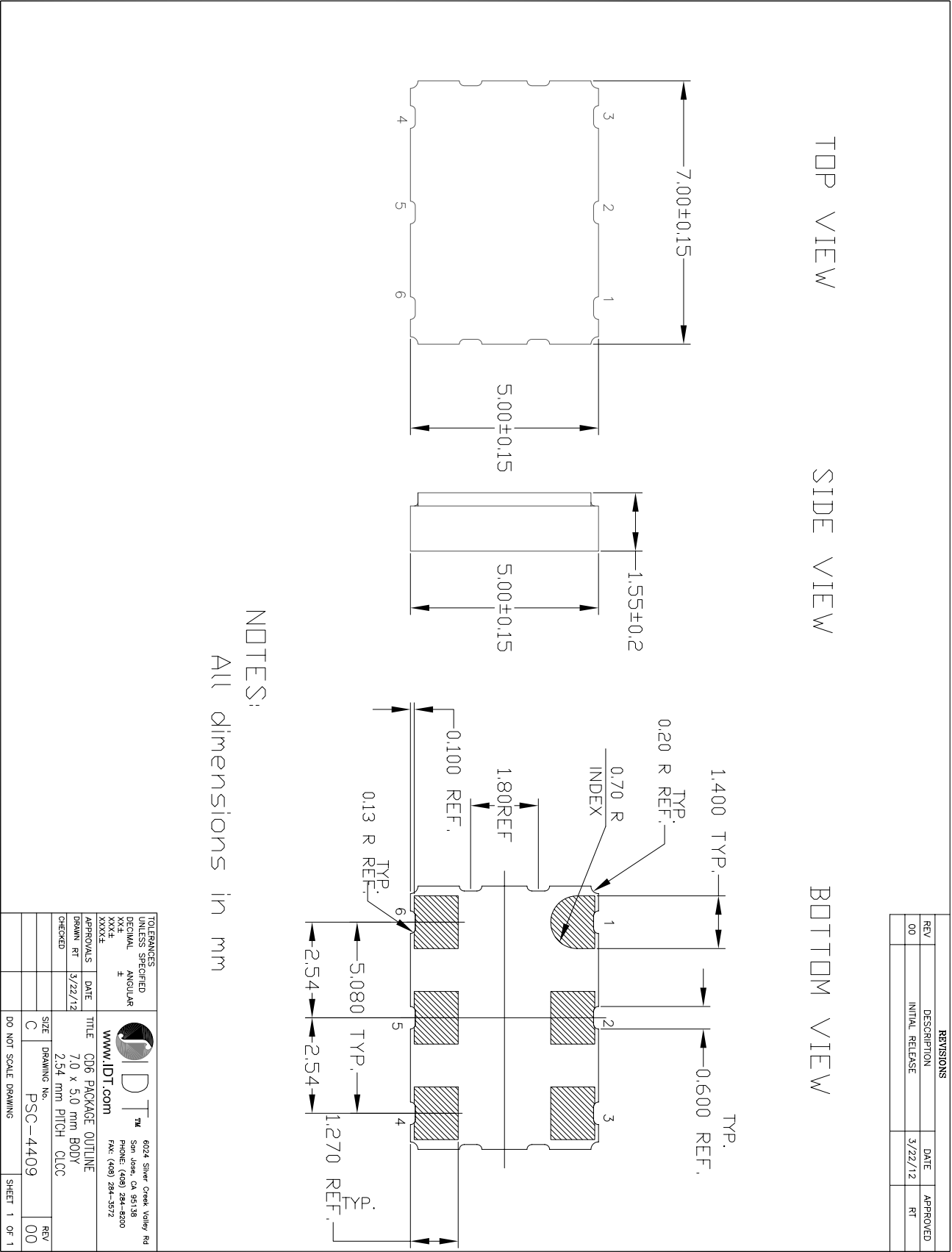
**Table 7.  $\theta_{JA}$  vs. Air Flow Table for a 6-lead Ceramic 5mm x 7mm Package**

| $\theta_{JA}$ vs. Air Flow                  |          |          |          |
|---------------------------------------------|----------|----------|----------|
| Meters per Second                           | 0        | 1        | 2        |
| Multi-Layer PCB, JEDEC Standard Test Boards | 49.4°C/W | 44.2°C/W | 42.1°C/W |

## Transistor Count

The transistor count for IDT8N3S270 is: 47,511

Package Outline and Package Dimensions





## Ordering Information for FemtoClock NG Ceramic-Package XO and VCXO Products

The programmable VCXO and XO devices support a variety of device options such as the output type, number of default frequencies, internal crystal frequency, power supply voltage, ambient temperature range and the frequency accuracy. The device options, default frequencies and default VCXO pull range must be specified at the time of order and are programmed by IDT before the shipment. The table below specifies the available order codes, including the device options and default frequency configurations. Example part number: the order code 8N3QV01FG-0001CDI specifies a programmable, quad default-frequency VCXO with a voltage supply of 2.5V, a LVPECL output, a  $\pm 50$ ppm crystal frequency accuracy,

contains a 114.285MHz internal crystal as frequency source, industrial temperature range, a lead-free (6/6 RoHS) 6-lead ceramic 5mm x 7mm x 1.55mm package and is factory-programmed to the default frequencies of 100MHz, 122.88MHz, 125MHz and 156.25MHz and to the VCXO pull range of minimum  $\pm 100$ ppm.

Other default frequencies and order codes are available from IDT on request. For more information on available default frequencies, see the *FemtoClock N Ceramic-Package XO and VCXO Ordering Product Information* document.

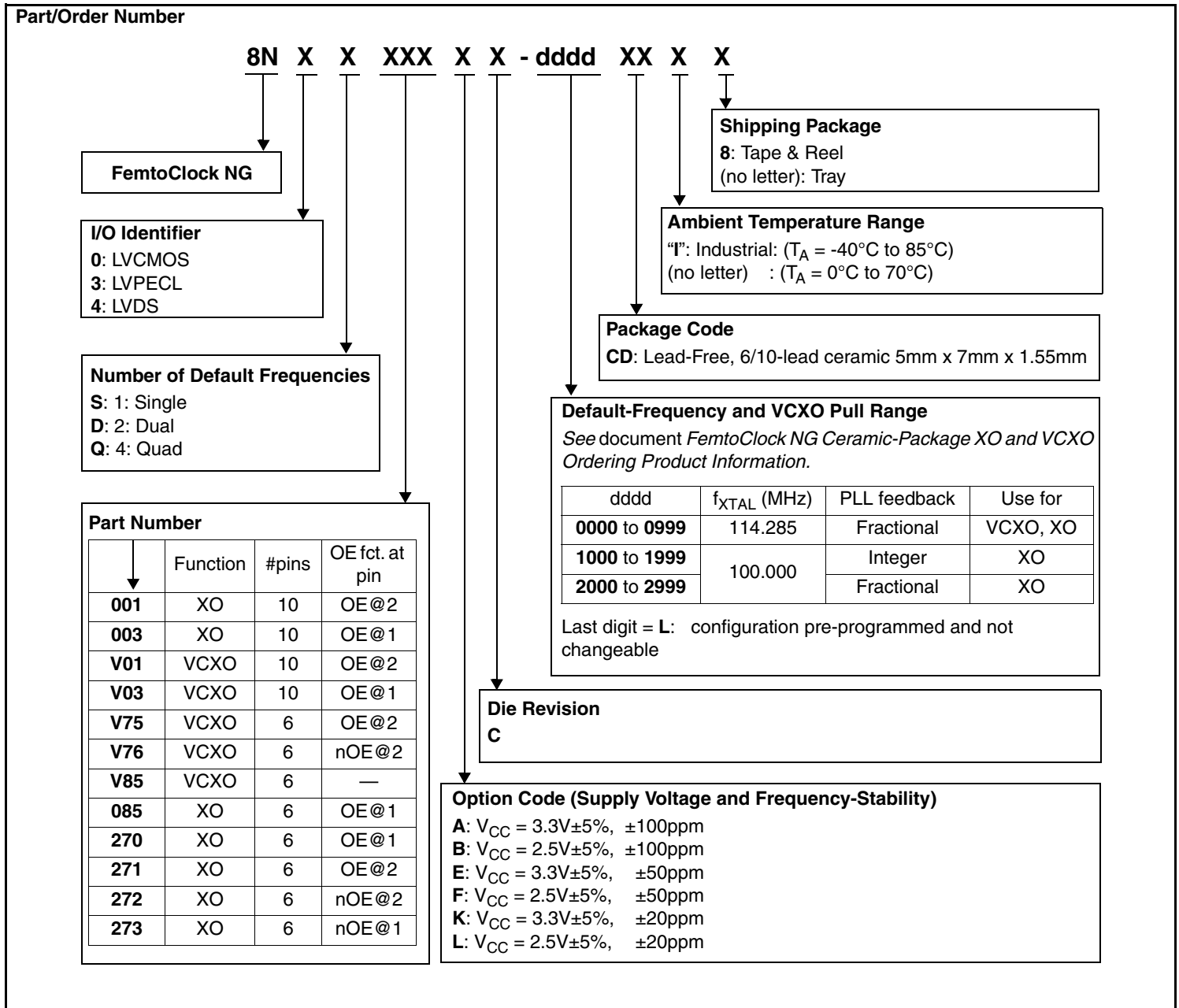


Table 8. Device Marking

| Marking | Industrial Temperature Range (T <sub>A</sub> = -40°C to 85°C) | Commercial Temperature Range (T <sub>A</sub> = 0°C to 70°C) |
|---------|---------------------------------------------------------------|-------------------------------------------------------------|
|         | IDT8N3S270yC-<br>ddddCDI                                      | IDT8N3S270yC-<br>ddddCD                                     |
|         | y = Option Code, dddd=Default-Frequency and VCXO Pull Range   |                                                             |

While the information presented herein has been checked for both accuracy and reliability, Integrated Device Technology (IDT) assumes no responsibility for either its use or for the infringement of any patents or other rights of third parties, which would result from its use. No other circuits, patents, or licenses are implied. This product is intended for use in normal commercial and industrial applications. Any other applications, such as those requiring high reliability or other extraordinary environmental requirements are not recommended without additional processing by IDT. IDT reserves the right to change any circuitry or specifications without notice. IDT does not authorize or warrant any IDT product for use in life support devices or critical medical instruments.

## We've Got Your Timing Solution



6024 Silver Creek Valley Road  
San Jose, California 95138

**Sales**

800-345-7015 (inside USA)  
+408-284-8200 (outside USA)  
Fax: 408-284-2775  
[www.IDT.com/go/contactIDT](http://www.IDT.com/go/contactIDT)

**Technical Support**

[netcom@idt.com](mailto:netcom@idt.com)  
+480-763-2056

DISCLAIMER Integrated Device Technology, Inc. (IDT) and its subsidiaries reserve the right to modify the products and/or specifications described herein at any time and at IDT's sole discretion. All information in this document, including descriptions of product features and performance, is subject to change without notice. Performance specifications and the operating parameters of the described products are determined in the independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are registered trademarks of IDT. Other trademarks and service marks used herein, including protected names, logos and designs, are the property of IDT or their respective third party owners.

Copyright 2012. All rights reserved.



**Стандарт  
Электрон  
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

**Наши контакты:**

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331